

LOW-VOLTAGE OPERATION DUAL C-MOS OPERATIONAL AMPLIFIER

■ GENERAL DESCRIPTION

The NJU7018 is a low voltage single-power-supply and low operating current dual C-MOS operational amplifier.

The input bias current is as low as less than 1pA consequently the very small signal around the ground level can be amplified.

The minimum operating voltage is 1V and the output stage permits output signals to swing between both of the supply rails.

Furthermore, the NJU7018 is packaged with a various small one therefore it can be especially applied to portable items.

■ PACKAGE OUTLINE



NJU7018D
(DIP8)



NJU7018M
(DMP8)



NJU7018V
(SSOP8)



NJU7018R
(MSOP8(VSP8))

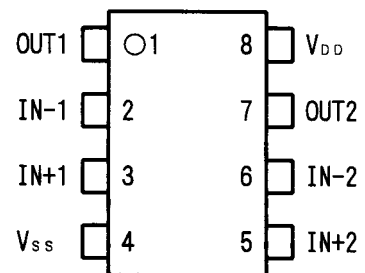


NJU7018RB1
(MSOP8(TVSP8))

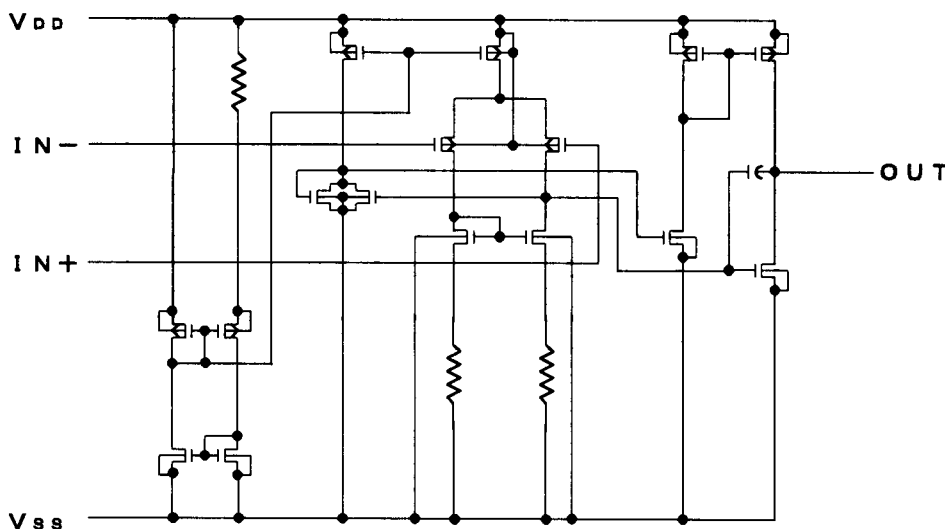
■ FEATURES

- Single-Power-Supply
- Wide Operating Voltage ($V_{DD}=1\sim 5.5V$)
- Wide Output Swing Range ($V_{OM}=2.9V$ min. @ 3.0V)
- Low Operating Current ($I_{DD}=0.75mA$ typ./circuit)
- Low Bias Current ($I_{IB}=1pA$ typ.)
- Internal Compensation Capacitor
- C-MOS Technology
- Package Outline DIP8,DMP8,SSOP8,
MSOP8(VSP8)MEETJEDEC MO-187-DA
MSOP8(TVSP8)MEETJEDEC MO-187-DA/THIN TYPE

■ PIN CONFIGURATION



■ EQUIVALENT CIRCUIT



■ ABSOLUTE MAXIMUM RATINGS

(Ta=25°C)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V_{IN}	7	V
Differential Input Voltage	V_{ID}	± 7 (note1)	V
Common Mode Input Voltage	V_{IC}	-0.3~7	V
Power Dissipation	P_D	(DIP8) 500 (DMP8) 300 (SSOP8) 250 (MSON8(VSP8/TVSP8)) 320	mW
Operating Temperature Range	T_{opr}	-40~+85	°C
Storage Temperature Range	T_{stg}	-55~+125	°C

(note1) If the supply voltage (V_{DD}) is less than 7V, the input voltage must not over the V_{DD} level though 7V is limit specified.

(note2) Decoupling capacitor should be connected between V_{DD} and V_{SS} due to the stabilized operation for the circuit.

■ ELECTRICAL CHARACTERISTICS

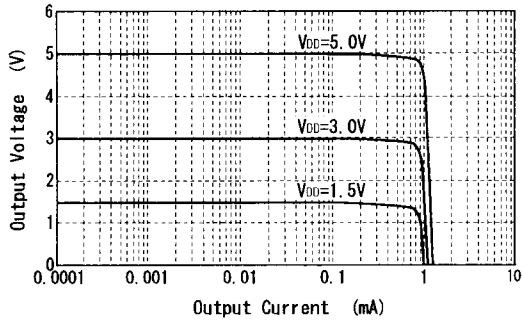
(Ta=25°C, $V_{DD}=3.0V, R_L=\infty$)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Input Offset Voltage	V_{IO}	$V_{IN}=1/2V_{DD}$	-	-	10	mV
Input Offset Current	I_{IO}		-	1	-	pA
Input Bias Current	I_{IB}		-	1	-	pA
Input Impedance	R_{IN}		-	1	-	TΩ
Large Signal Voltage Gain	A_{VD}		60	70	-	dB
Input Common Mode Voltage Range	V_{ICM}		0~2.5	-	-	V
Maximum Output Swing Voltage	V_{OM1}	$R_L=16k\Omega$	$V_{DD}-0.1$	-	-	V
	V_{OM2}	$R_L=16k\Omega$	-	-	$V_{SS}+0.1$	V
Common Mode Rejection Ratio	CMR	$V_{IN}=1/2V_{DD}$	55	65	-	dB
Supply Voltage Rejection Ratio	SVR	$V_{DD}=1.5\sim 5.5V$	60	70	-	dB
Operating Current	I_{DD}	Per Circuit	-	0.75	1.5	mA
Slew Rate	SR		-	3.7	-	V/μs
Unity Gain Bandwidth	F_t	$A_v=40dB, C_L=10pF$	-	1.0	-	MHz

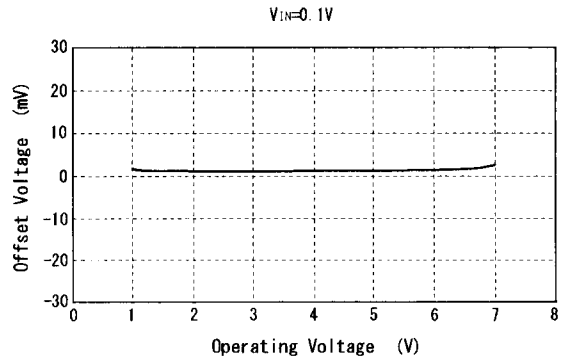
(note3) The source current is less than 181μA (at $V_{OM}/R_L=2.9V/16k\Omega$).

■ TYPICAL CHARACTERISTICS

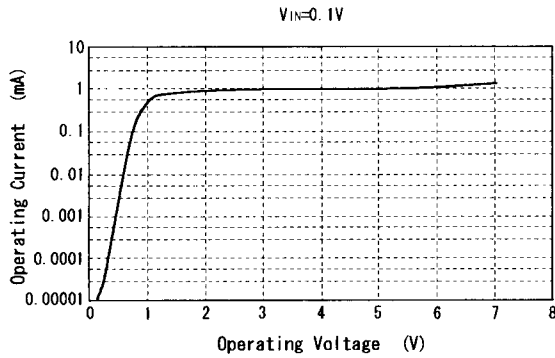
Output Voltage vs. Output Current (SOURCE)



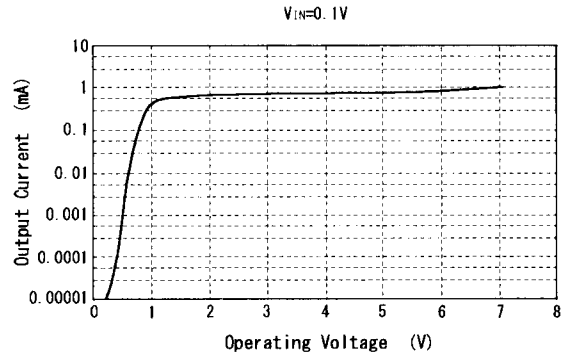
Offset Voltage vs. Operating Voltage



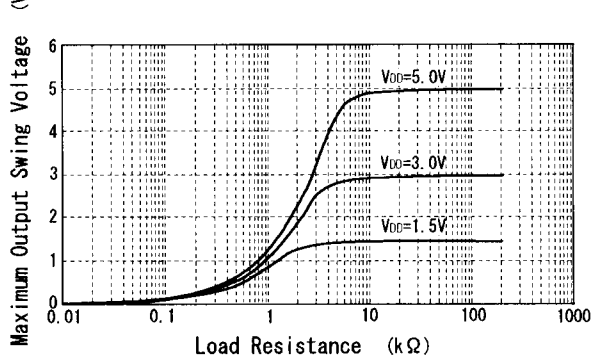
Operating Current vs. Operating Voltage



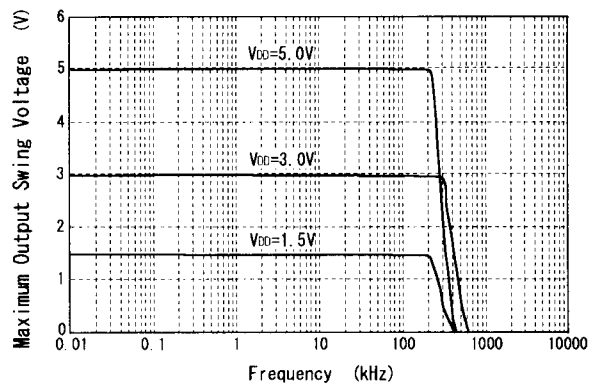
Output Current vs. Operating Voltage



Maximum Output Swing Voltage vs. Load Resistance

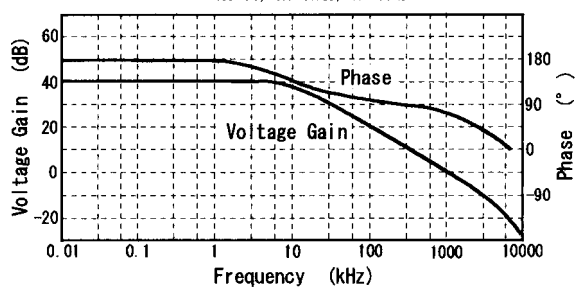


Maximum Output Swing Voltage vs. Frequency



Voltage Gain·Phase vs. Frequency

$V_{DD}=3V$, $R_s=1k\Omega$, $A_v=40dB$



[CAUTION]

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